# **Preliminary**

TOSHIBA Photocoupler GaAlAs IRED + Photo IC

# **TLP350**

Industrial Inverter

Inverter for Air Conditioner

IGBT/Power MOSFET Gate Drive

IH(Induction Heating)

The TOSHIBA TLP350 consists of a GaAlAs light-emitting diode and an integrated photodetector.

This unit is an 8-lead DIP package.

The TLP350 is suitable for gate driving IGBTs or power MOSFETs.

- Peak output current:  $I_0 = \pm 2.5 A$  (max)
- Guaranteed performance over temperature: -40 to 100°C
- Supply current:Icc = 2 mA (max)
- Power supply voltage: Vcc = 15 to 30 V
- Threshold input current : IFLH = 5 mA (max)
- Switching time (t<sub>pLH</sub>/t<sub>pHL</sub>) : 500 ns (max)
- Common mode transient immunity:  $15 \text{ kV/}\mu\text{s}$
- Isolation voltage: 3750 Vrms
- UL Recognized : UL1577,File No.E67349
- Option(D4)

VDE Approved: DIN EN60747-5-2

 $\begin{aligned} & \text{Maximum Operating Insulation Voltage}: 890 V_{PK} \\ & \text{Highest Permissible Over Voltage} \end{aligned} : 4000 V_{PK} \end{aligned}$ 

(Note):When a EN60747-5-2 approved type is needed, Please designate "Option(D4)"

#### 8 7 6 5 1 2 3 4 9.66±0.25 9.66±0.25 9.60

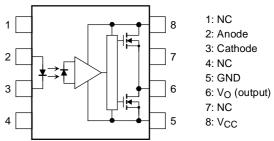
Unit: mm

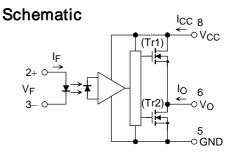
Weight: 0.54 g (typ.)

#### **Truth Table**

Input	LED	Tr1	Tr2	Output
Н	ON	ON	OFF	Н
L	OFF	OFF	ON	L

#### Pin Configuration (top view)





A 0.1  $\mu$ F bypass capacitor must be connected between pins 8 and 5. (See Note 6)



#### Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	lF	20	mA	
	Forward current de-rating (Ta ≥	ΔΙ <sub>Γ</sub> /ΔΤα	-0.54	mA/°C	
LED	Peak transient forward current	(Note 1)	I <sub>FP</sub>	1	Α
	Reverse voltage	VR	5	V	
	Junction temperature	Tj	125	°C	
	"H" peak output current	Ta = -40 to 100°C	I <sub>OPH</sub>	-2.5	А
ъ	"L" peak output current	(Note 2)	I <sub>OPL</sub>	2.5	А
Detector	Supply voltage	Ta < 95 °C	V <sub>CC</sub>	35	V
ă	Supply voltage Derating	Ta≥95 °C	V <sub>CC</sub> / Ta	-1.0	V /
	Junction temperature		Tj	125	°C
Ope	rating frequency	(Note 3)	f	50	kHz
Stora	age temperature range	T <sub>stg</sub>	-55 to 125	°C	
Ope	rating temperature range	T <sub>opr</sub>	-40 to 100	°C	
Lead	soldering temperature (10 s)	T <sub>sol</sub>	260	°C	
Isola	tion voltage (AC, 1 minute, R.H. ≤	≤ 60%) (Note 5)	BVS	3750	Vrms

Note 1: Pulse width  $P_W \le 1 \mu s$ , 300 pps

Note 2: Exponential waveform pulse width  $P_W \le 0.3 \mu s$ ,  $f \le 15 kHz$ 

Note 3: Exponential waveform  $I_{OPH} \ge -2.0A (\le 0.3 \mu s)$ ,  $I_{OPL} \le 2.0A (\le 0.3 \mu s)$ 

Note 4: At 2 mm or more from the lead root.

Note 5: This device is regarded as a two terminal device: pins 1, 2, 3 and 4 are shorted together, as are pins 5, 6, 7 and 8.

Note 6: A ceramic capacitor  $(0.1 \, \mu F)$  should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypass may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.

#### **Recommended Operating Conditions**

Characteristic		Symbol	Min	Тур.	Max	Unit
Input current, ON	(Note 7)	I <sub>F (ON)</sub>	7.5	_	10	mA
Input voltage, OFF		V <sub>F</sub> (OFF)	0	_	0.8	V
Supply voltage		V <sub>CC</sub>	15	_	30	V
Peak output current		I <sub>OPH</sub> /I <sub>OPL</sub>	_	_	±2.0	Α
Operating temperature		T <sub>opr</sub>	-40	_	100	°C

Note 7: Input signal rise time (fall time)  $< 0.5 \mu s$ .

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#### Electrical Characteristics (Ta = -40 to 100°C, unless otherwise specified)

Characteristic		Symbol	Test Circuit	Test C	Conditions	Min	Тур.*	Max	Unit
Forward voltage		V <sub>F</sub>	_	$I_F = 10 \text{ mA}, Ta = 25^{\circ}\text{C}$		_	1.6	1.8	V
Temperature coefficient of forward voltage		ΔV <sub>F</sub> /ΔΤα	_	I <sub>F</sub> = 10 mA		_	-2.0	_	mV/°C
Input reverse current		I <sub>R</sub>	_	V <sub>R</sub> = 5 V, Ta = 25°C		_	_	10	μА
Input capacitance		C <sub>T</sub>	_	V = 0 , f = 1 MHz,Ta = 25°C		_	45	250	pF
Output current (Note 8)	"H" Level	Іорн	1	$V_{CC} = 30 \text{ V,I}_F = 5 \text{ mA}$ $V_{8-6} = -3.5 \text{ V}$		_	-1.6	-1.0	
	n Level	ЮРН	'	V <sub>CC</sub> = 15 V,I <sub>F</sub> = 5 mA V <sub>8-6</sub> = -7.0 V		_	_	-2.0	_
	<i>(4)</i> N. I	1	0	$V_{CC} = 30 \text{ V,I}_F = 0 \text{ mA}$ $V_{6-5} = 2.5 \text{V}$		1.0	1.6	_	A
	"L" Level	"L" Level I <sub>OPL</sub>	2	$V_{CC} = 15 \text{ V,I}_F = 0 \text{ mA}$ $V_{6-5} = 7.0 \text{V}$		2.0	_	_	
O to toolke as	"H" Level	V <sub>OH</sub>	3	V <sub>CC 1</sub> = +15 V V <sub>EE 1</sub> = -15 V	I <sub>F</sub> = 5 mA	11	13.7	_	V
Output voltage	"L" Level	V <sub>OL</sub>	4	R <sub>L</sub> = 200	V <sub>F</sub> = 0.8 V	_	-14.9	-12.5	ľ
Supply current	"H" Level	Icch	5	V <sub>CC</sub> = 30 V	I <sub>F</sub> = 10 mA	_	1.3	2.0	mA
Зирріу сипені	"L" Level	ICCL	6	V <sub>O</sub> open	I <sub>F</sub> = 0 mA		1.3	2.0	IIIA
Threshold input current	$L \rightarrow H$	I <sub>FLH</sub>	_	V <sub>CC</sub> = 15V , V <sub>O</sub> > 1V , Io = 0mA		_	1.8	5	mA
Threshold input voltage	$H \rightarrow L$	V <sub>FHL</sub>	_	$V_{CC} = 15V$ , $V_O < 1V$ , $IO = 0mA$		0.8	_	_	V
Supply voltage		V <sub>CC</sub>	_	_		15	_	30	V
UVLO threshhold		V <sub>UVLO+</sub>	_	V <sub>O</sub> > 2.5 V , I <sub>F</sub> = 5 mA		11.0	12.5	13.5	V
		V <sub>UVLO</sub> -	_			9.5	11.0	12.0	V
UVLO hysteresis		UVLO <sub>HYS</sub>					1.5		V

<sup>\*:</sup> All typical values are at Ta = 25°C

Note 8: Duration of I<sub>O</sub> :  $\leq$  50  $\mu$ s(1PULSE)

Note 9: This product is more sensitive to static electricity (ESD) than the conventional product because of its minimal power consumption design.

General static electricity precautions are necessary for handling this component.

## Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Capacitance input to output	Cs	V = 0,f = 1MHz (Note6)	_	1.0	_	pF
Isolation resistance	Rs	$V_S = 500 \text{ V}, \text{Ta} = 25^{\circ}\text{C},$ R.H. $\leq 60\%$ (Note6)	1×10 <sup>12</sup>	10 <sup>14</sup>	_	Ω
		AC,1 minute	3750	_	_	V
Isolation voltage	$BV_S$	AC,1 second,in oil	_	10000	_	V <sub>rms</sub>
		DC,1 minute,in oil	_	10000	_	Vdc

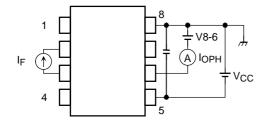
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## Switching Characteristics (Ta = -40 to 100°C, unless otherwise specified)

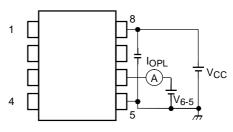
Characteristic		Symbol	Test Circuit	Test Cor	nditions	Min	Тур.*	Max	Unit
Propagation delay time	$L \rightarrow H$	t <sub>pLH</sub>		$V_{CC} = 30 \text{ V}$ $R_g = 20 \Omega$ $C_g = 10 \text{ nF}$	$I_F = 0 \rightarrow 5 \text{ mA}$	50	260	500	
	$H \rightarrow L$	t <sub>pHL</sub>			$I_F = 5 \rightarrow 0 \text{ mA}$	50	260	500	
Switching Time Dispersion between ON and OFF		tpHL-tpLH	7	$\begin{aligned} &V_{CC}=30 \text{ V} \\ &R_g=20 \Omega, \\ &C_g=10 \text{ nF} \end{aligned}$				350	ns
Output rise time (10-90%)		t <sub>r</sub>		V <sub>CC</sub> = 30 V	$I_F = 0 \rightarrow 5 \text{ mA}$	_	15	_	
Output fall time (90-10%)		t <sub>f</sub>		$R_g = 20 \Omega$ $C_g = 10 \text{ nF}$	$I_F = 5 \rightarrow 0 \text{ mA}$	_	8	_	
Common mode transient immunity at high level output		СМН		$V_{CM} = 1000 \text{ Vp-p}$ 8 Ta = 25°C	I <sub>F</sub> = 5 mA V <sub>O (min)</sub> =26V	-15000	_	_	V/µs
Common mode transient immunity at low level output		CML	0		I <sub>F</sub> = 0 mA V <sub>O (max)</sub> =1V	15000	_	_	ν/μ5

<sup>\*:</sup> All typical values are at Ta = 25°C

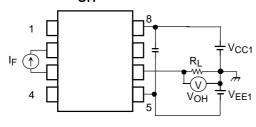
## Test Circuit 1: I<sub>OPH</sub>



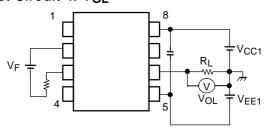
#### Test Circuit 2: IOPL



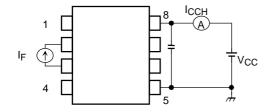
Test Circuit 3: V<sub>OH</sub>



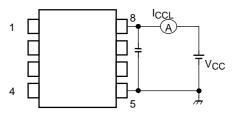
Test Circuit 4: V<sub>OL</sub>



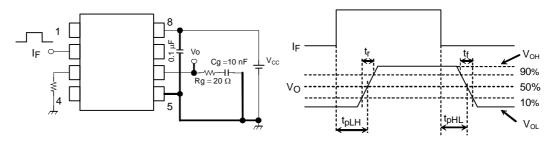
Test Circuit 5: I<sub>CCH</sub>



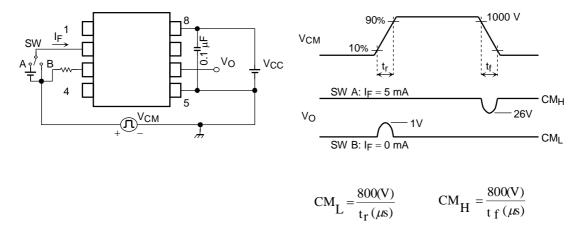
Test Circuit 6: I<sub>CCL</sub>



## Test Circuit 7: $t_{pLH}$ , $t_{pHL}$ , $t_{r}$ , $t_{f}$ , PDD

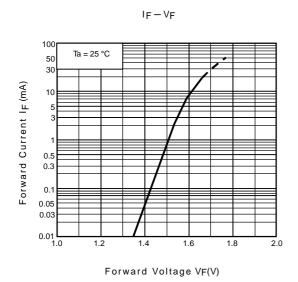


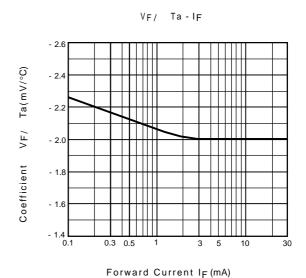
## Test Circuit 8: CMH, CML

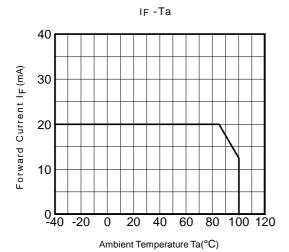


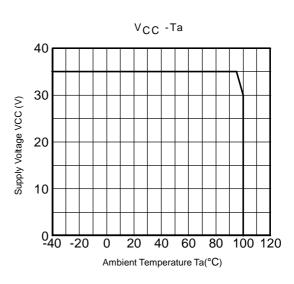
CML (CMH) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.

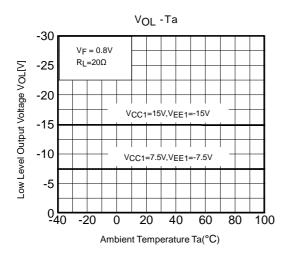
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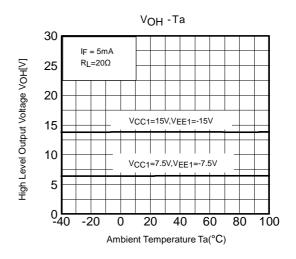




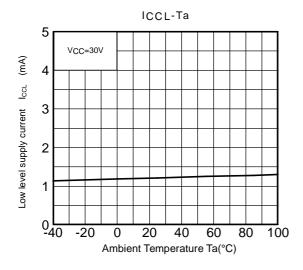


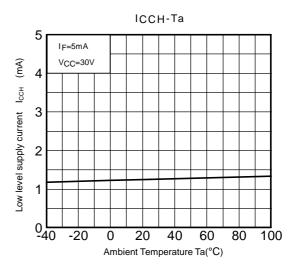


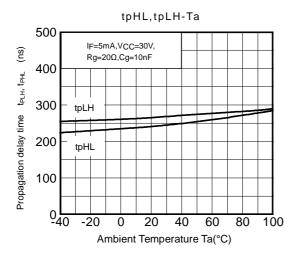


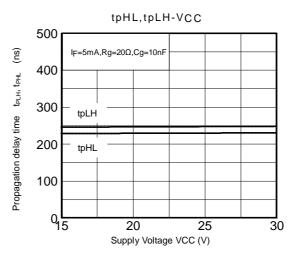


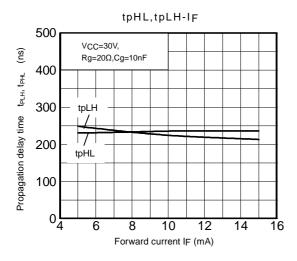
<sup>\*:</sup> The above graphs show typical characteristics.

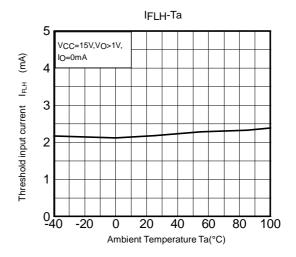




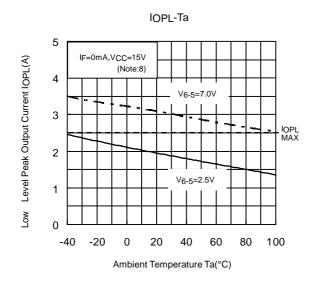


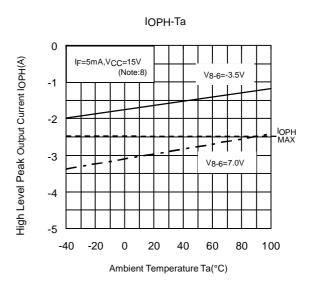


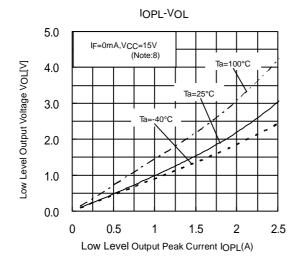


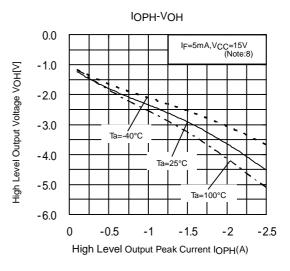


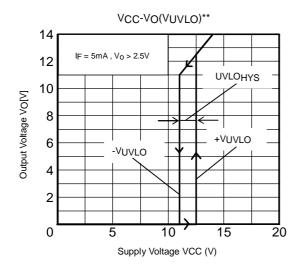
<sup>\*:</sup> The above graphs show typical characteristics.

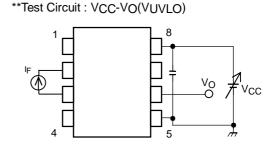












<sup>\*:</sup> The above graphs show typical characteristics.

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Handbook" etc..

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